

**RL201
THRU
RL207**

Features

- Low Cost
- Low Leakage
- Low Forward Voltage Drop
- High Current Capability

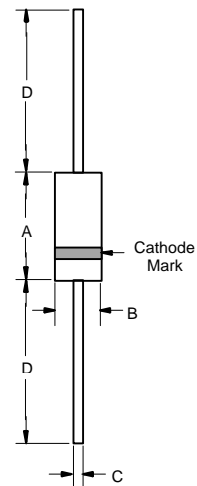
**2 Amp
Silicon Rectifier
50 to 1000 Volts**

Maximum Ratings

- Operating Temperature: -65°C to +175°C
- Storage Temperature: -65°C to +175°C
- Typical Thermal Resistance (R_{θJA}) 40°C/W

Microsemi Catalog Number	Device Marking	Maximum Recurrent Peak Reverse Voltage	Maximum RMS Voltage	Maximum DC Blocking Voltage
RL201	---	50V	35V	50V
RL202	---	100V	70V	100V
RL203	---	200V	40V	200V
RL204	---	400V	280V	400V
RL205	---	600V	420V	600V
RL206	---	800V	560V	800V
RL207	---	1000V	700V	1000V

DO-15



Electrical Characteristics @ 25°C Unless Otherwise Specified

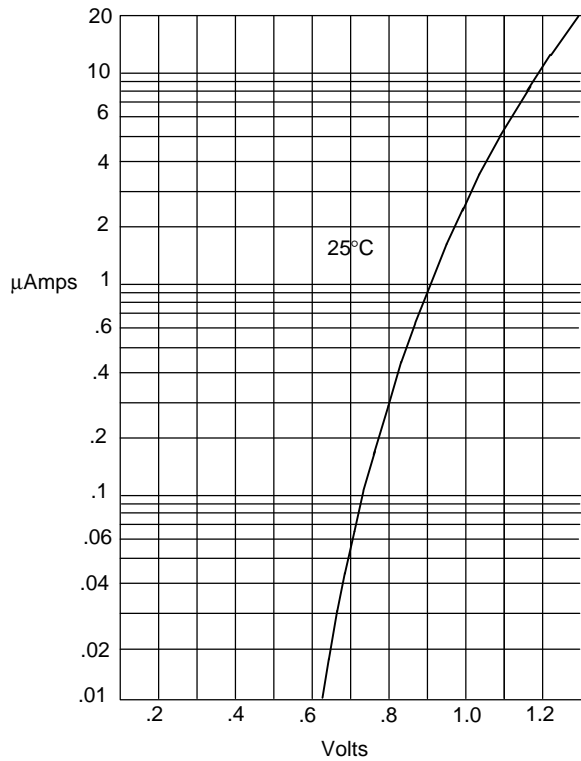
Average Forward Current	I _{F(AV)}	2 A	T _A = 75°C
Peak Forward Surge Current	I _{FSM}	70A	8.3ms, half sine
Maximum Instantaneous Forward Voltage	V _F	1.0V	I _{FM} = 2.0A; T _A = 25°C
Maximum DC Reverse Current At Rated DC Blocking Voltage	I _R	5.0μA 50μA	T _A = 25°C T _A = 100°C
Typical Junction Capacitance	C _J	20pF	Measured at 1.0MHz, V _R =4.0V

*Pulse Test: Pulse Width 300μsec, Duty Cycle 1%

DIM	DIMENSIONS				NOTE
	INCHES		MM		
A	.230	.300	5.80	7.60	
B	.104	.140	2.60	3.60	
C	.026	.034	.70	.90	
D	1.000	---	25.40	---	

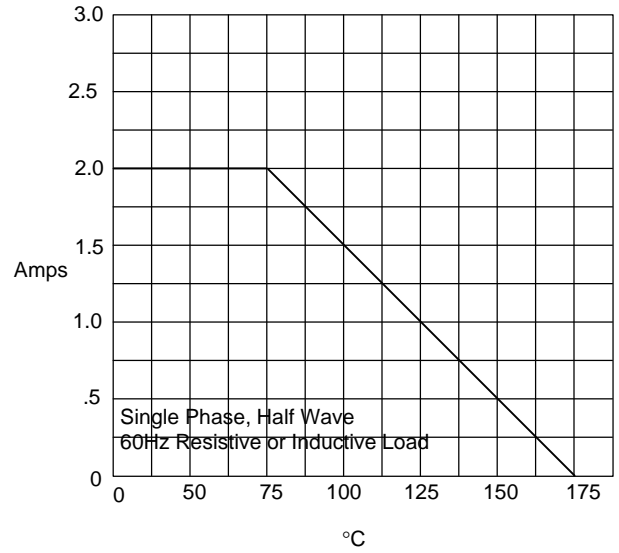
RL201 thru RL207

Figure 1
Typical Forward Characteristics



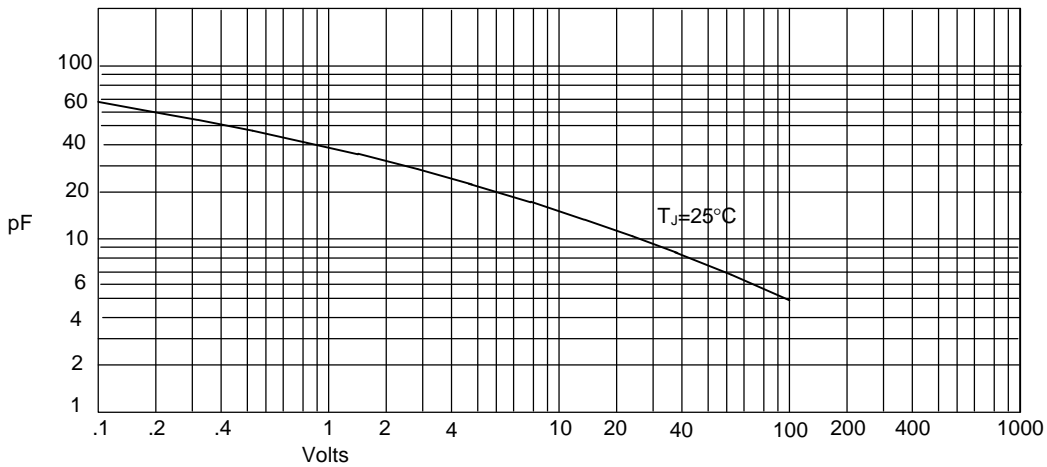
Instantaneous Forward Current - MicroAmperes *versus*
Instantaneous Forward Voltage - Volts

Figure 2
Forward Derating Curve



Average Forward Rectified Current - Amperes *versus*
Ambient Temperature - °C

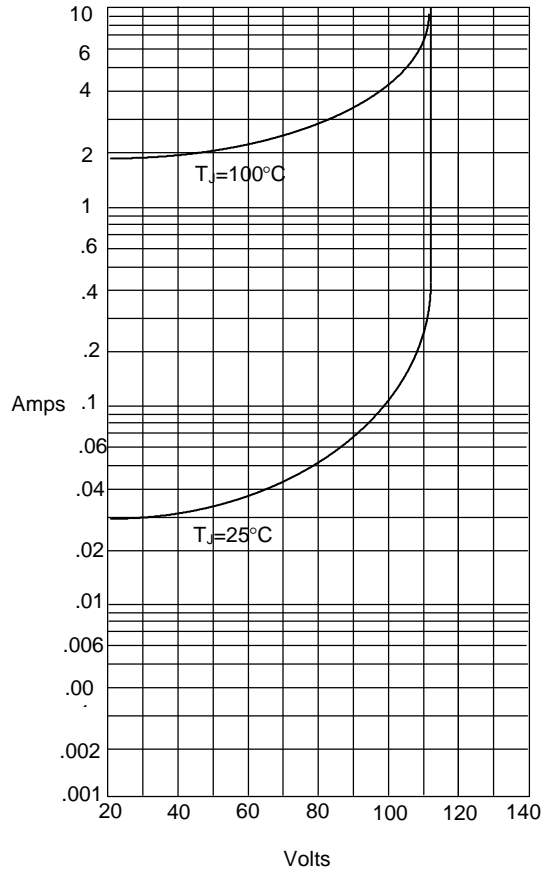
Figure 3
Junction Capacitance



Junction Capacitance - pF *versus*
Reverse Voltage - Volts

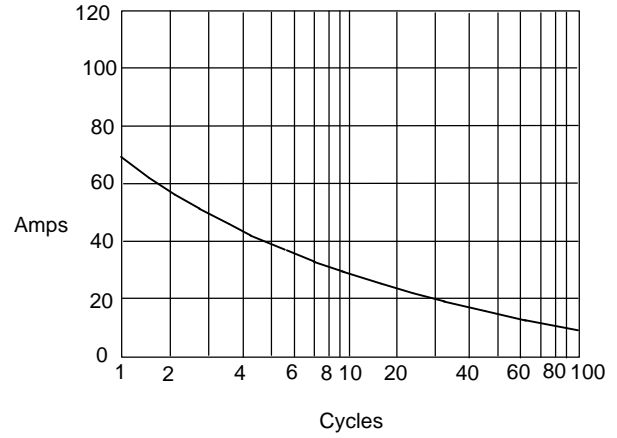
RL201 thru RL207

Figure 4
Typical Reverse Characteristics



Instantaneous Reverse Current - Amperes versus
Percent Of Rated Peak Reverse Voltage - Volts

Figure 5
Peak Forward Surge Current



Peak Forward Surge Current - Amperes versus
Number Of Cycles At 60Hz - Cycles